Power MOSFET -60 V, -2.6 A, Single P-Channel SOT-223

Features

- Design for low R_{DS(on)}
- Withstands High Energy in Avalanche and Commutation Modes
- AEC-Q101 Qualified NVF2955
- These Devices are Pb-Free and are RoHS Compliant

Applications

- Power Supplies
- PWM Motor Control
- Converters
- Power Management

MAXIMUM RATINGS (T_J = 25° C unless otherwise noted)

Parame	eter		Symbol	Value	Unit
Drain-to-Source Voltage	Drain-to-Source Voltage				V
Gate-to-Source Voltage	V _{GS}	±20	V		
Continuous Drain	Steady T _A = 25°C		I _D	-2.6	А
Current (Note 1)	State	T _A = 85°C		-2.0	
Power Dissipation (Note 1)	Steady State	$T_A = 25^{\circ}C$	P _D	2.3	W
Continuous Drain	Steady State	$T_A = 25^{\circ}C$	۱ _D	-1.7	А
Current (Note 2)	State	$T_A = 85^{\circ}C$		-1.3	
Power Dissipation (Note 2)		$T_A = 25^{\circ}C$	PD	1.0	W
Pulsed Drain Current	tp =	= 10 μs	I _{DM}	-17	А
Operating Junction and St	T _J , T _{STG}	–55 to 175	°C		
Single Pulse Drain-to-So Energy (V _{DD} = 25 V, V _G = L = 10 mH, R _G = 25 Ω)	EAS	225	mJ		
Lead Temperature for Sold (1/8" from case for 10 sect		ooses	ΤL	260	°C

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Max	Unit
Junction-to-Tab (Drain) - Steady State (Note 2)	$R_{\theta JC}$	14	
Junction-to-Ambient - Steady State (Note 1)	$R_{\theta JA}$	65	°C/W
Junction-to-Ambient - Steady State (Note 2)	$R_{\theta JA}$	150	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. When surface mounted to an FR4 board using 1 in. pad size (Cu. area = 1.127 in² [1 oz] including traces)

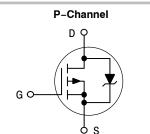
2. When surface mounted to an FR4 board using the minimum recommended pad size (Cu. area = 0.341 in^2)



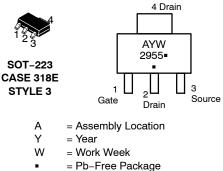
ON Semiconductor®

http://onsemi.com

V _{(BR)DSS}	R _{DS(on)} TYP	I _D MAX
–60 V	145 mΩ @ –10 V	–2.6 A







(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
NTF2955T1G	SOT–223 (Pb–Free)	1000 /Tape & Reel
NVF2955T1G	SOT-223 (Pb-Free)	1000/ Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS (TJ=25°C unless otherwise stated)

Parameter	Symbol	Test Condition		Min	Тур	Max	Unit
OFF CHARACTERISTICS							
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	V_{GS} = 0 V, I_D = –250 μ A		-60			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} /T _J				66.4		mV/°C
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V,$ $T_{J} = 25^{\circ}C$ $V_{DS} = -60 V$				-1.0	μΑ
		V _{DS} = -60 V	T _J = 125°C			-50	
Gate-to-Source Leakage Current	I _{GSS}	V _{DS} = 0 V, V	/ _{GS} = ±20 V			±100	nA

ON CHARACTERISTICS (Note 3)

Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}, I_D = -1.0 \text{ mA}$	-2.0		-4.0	V
Drain-to-Source On Resistance	R _{DS(on)}	V_{GS} = -10 V, I _D = -0.75 A		145	170	mΩ
		V _{GS} = –10 V, I _D = –1.5 A		150	180	
		V _{GS} = -10 V, I _D = -2.4 A		154	185	
Forward Transconductance	9 FS	V_{GS} = -15 V, I _D = -0.75 A		1.77		S

CHARGES AND CAPACITANCES

Input Capacitance	C _{ISS}	V _{GS} = 0 V, f = 1.0 MHz, V _{DS} = 25 V	492	pF
Output Capacitance	C _{OSS}	v _{DS} = 25 v	165	
Reverse Transfer Capacitance	C _{RSS}		50	
Total Gate Charge	Q _{G(TOT)}	$V_{GS} = 10 \text{ V}, V_{DS} = 30 \text{ V},$ $I_{D} = 1.5 \text{ A}$	14.3	nC
Threshold Gate Charge	Q _{G(TH)}	т _D = 1.5 А	1.2	
Gate-to-Source Charge	Q _{GS}		2.3	
Gate-to-Drain Charge	Q _{GD}		5.2	

SWITCHING CHARACTERISTICS (Note 4)

Turn-On Delay Time	t _{d(ON)}	$V_{GS} = 10 \text{ V}, V_{DD} = 25 \text{ V},$	11	ns
Rise Time	t _r	I_D = 1.5 A, R_G = 9.1 Ω R_L = 25 Ω	7.6	
Turn-Off Delay Time	t _{d(OFF)}		65	
Fall Time	t _f		38	

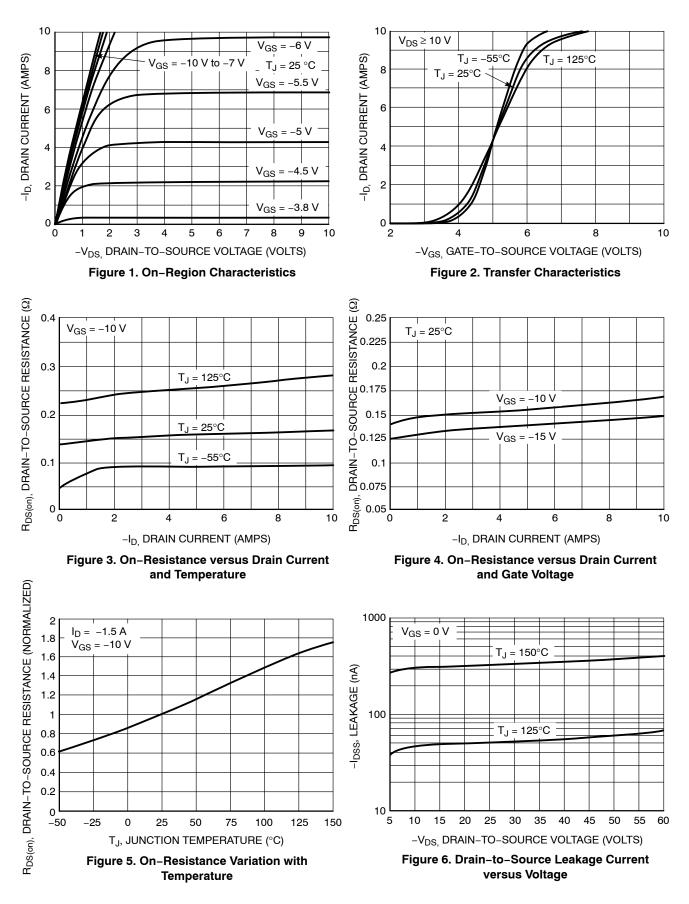
DRAIN-SOURCE DIODE CHARACTERISTICS

Forward Diode Voltage	V _{SD}	$V_{GS} = 0 V,$	$T_J = 25^{\circ}C$	-1.10	-1.30	V
		I _S = 1.5 A	T _J = 125°C	-0.9		
Reverse Recovery Time	t _{RR}	V _{GS} = 0 V, dI _S /dt = 100 A/µs, I _S = 1.5 A		36		
Charge Time	ta			20		ns
Discharge Time	t _b			16		
Reverse Recovery Charge	Q _{RR}			0.139		nC

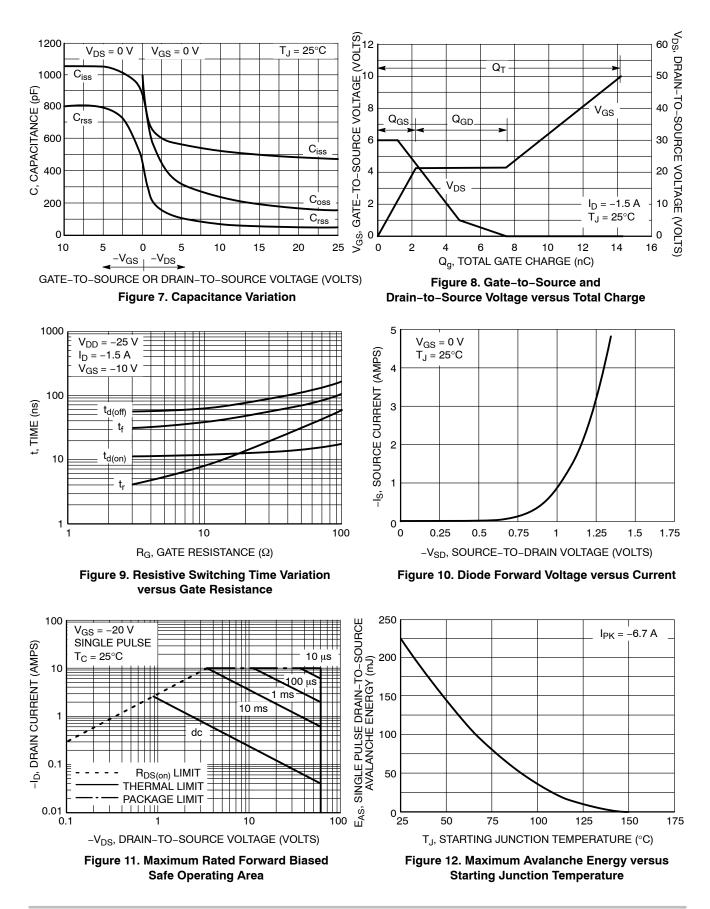
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 3. Pulse Test: pulse width \leq 300 μ s, duty cycle \leq 2%.

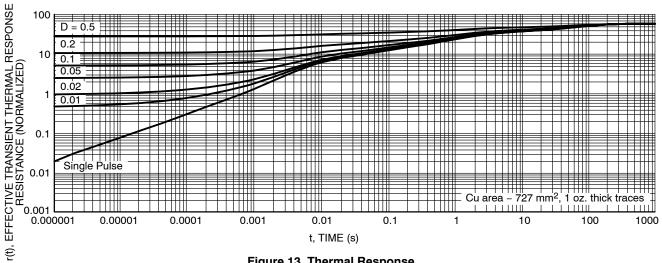
4. Switching characteristics are independent of operating junction temperatures.

TYPICAL PERFORMANCE CURVES (T_J = 25° C unless otherwise noted)



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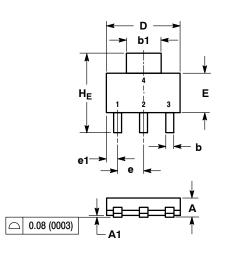






PACKAGE DIMENSIONS

SOT-223 (TO-261) CASE 318E-04 ISSUE N



NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: INCH.

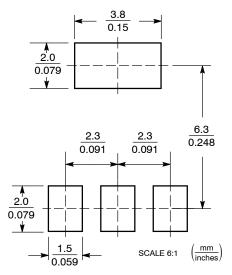
	м	ILLIMETE	RS		INCHES	
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	1.50	1.63	1.75	0.060	0.064	0.068
A1	0.02	0.06	0.10	0.001	0.002	0.004
b	0.60	0.75	0.89	0.024	0.030	0.035
b1	2.90	3.06	3.20	0.115	0.121	0.126
С	0.24	0.29	0.35	0.009	0.012	0.014
D	6.30	6.50	6.70	0.249	0.256	0.263
Е	3.30	3.50	3.70	0.130	0.138	0.145
е	2.20	2.30	2.40	0.087	0.091	0.094
e1	0.85	0.94	1.05	0.033	0.037	0.041
L	0.20			0.008		
L1	1.50	1.75	2.00	0.060	0.069	0.078
HE	6.70	7.00	7.30	0.264	0.276	0.287
θ	0°	-	10°	0°	-	10°

3. 4.

STYLE 3: PIN 1. GATE 2. DRAIN

SOURCE DRAIN

SOLDERING FOOTPRINT*



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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